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Equipment for Collaborative Research in 2026

1. Material preparation group

1-1 Electron Beam Lithography & Ion Milling System

Building No. 2, Room 211

Microfabrication at a sub-micron scale can be performed by a 50-kV thermionic electron gun to obtain micro-sized structures of approximately 100 nm. Photolithography in combination with electron beam lithography equipment using a photomask aligner with large-area processing can be used to fabricate devices. An attached secondary ion mass spectrometer enables depth profile measurement using ion milling.

ELIONIX: ELS-7500 (2003)



1-2 Multi-Target Reactive Sputtering (Ion Beam Sputtering)

Building No. 2, Room 111

This multi-target reactive sputtering (ion beam sputtering) system enables the preparation of thin films/multi-layer samples without Ar plasma damage. This sputtering system consists of three ion source guns for sputtering and one ion milling gun for cleaning. There are six sputtering targets that can be installed in the deposition chamber.

Toei Scientific Industrial Co., Ltd: 3000HC (1989)

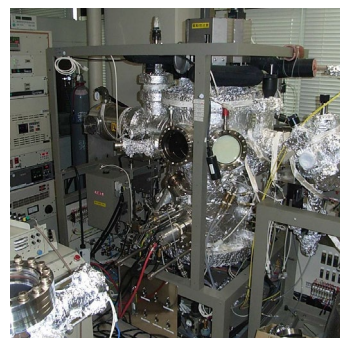


1-3 Reflection High-Energy Electron Diffraction System

Building No. 2, Room 111

This system consists of a main deposition chamber and a load lock chamber. In the main deposition chamber, epitaxial thin films/metallic superlattice samples can be developed while monitoring the film growth by reflection high-energy electron diffraction (RHEED). This RHEED system has a 30 kV-accelerated electron gun and a 150 mm-diameter screen. Moreover, a PC software for monitoring and analyzing RHEED patterns is available.

(1997)

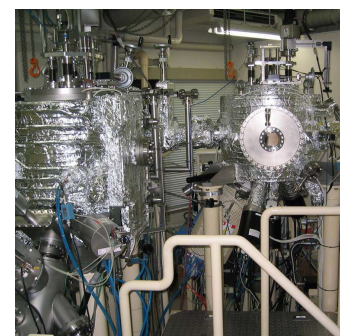


1-4 Multi-Ion Vapor Deposition System

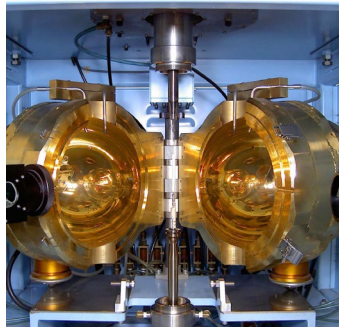
Building No. 2, Room 104

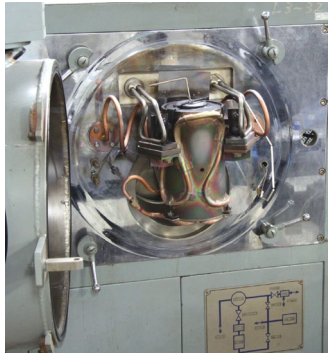
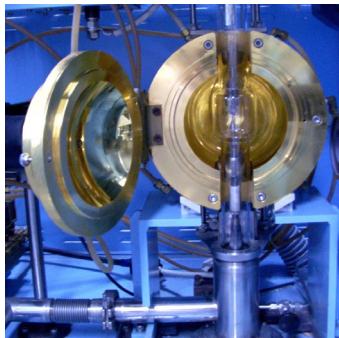
This is a thin-film deposition system equipped with magnetron sputtering cathodes. This deposition system also consists of an electron cyclotron resonance ion source for Ar milling and surface modification. In addition, a Freeman ion source enables ion implantation and dynamic mixing of samples, and its maximum acceleration voltage is 50 kV.

ULVAC: MB98 (1999)



1-5 Multi-Layer Chemical Vapor Deposition Reactor Building No. 2, Room 111 This is an apparatus for fabricating thin films by chemical vapor deposition (CVD) using electron cyclotron resonance (ECR) plasma. The high density and high ionization rate of the plasma in this equipment enables a high deposition rate, excellent step coverage, and low-temperature synthesis of thin films. Sumitomo Metal Industries, Ltd.: ES-037 (1988)	
1-6 Hot Working (Forging) Simulator Building No. 2, Room B06A Heat treatment under various conditions, high-temperature tensile/compressive deformation, powder sintering, and material phase transformation measurement can be performed using this equipment. Fuji Electronic Industrial Co., Ltd.: Thermecmastor-Z (2009)	
1-7 Spark Plasma Sintering: SPS-1050 Building No. 2, Room B01 This is a powder consolidation machine that uses the spark plasma sintering method. The raw material powder is filled in the conductive mold and is compressed by the top and bottom punches. A large pulsed current flowing through the mold generates heat for the sintering. Owing to the rapid heating effect, the grain growth can be suppressed and fine-structured compact specimens can be obtained. Sumiseki Materials Co., Ltd: DR.SINTER Model SPS-1050 (1992)	
1-8 Spark Plasma Sintering: SPS-3.20, Mark IV Building No. 2, Room B04 This is a powder consolidation machine that uses the spark plasma sintering method. The raw material powder is filled in the conductive mold and is compressed by the top and bottom punches. A large pulsed current flowing through the mold generates heat for the sintering. Owing to the rapid heating effect, grain growth can be suppressed and fine-structured compact specimens can be obtained. Compared with the SPS-1050, a larger current (8000 A) and a higher load (20 ton) can be applied in this equipment; this is useful for preparing large compact specimens. SPS SYNTEX INC: DR.SINTER Model SPS-3.20 Mark IV (2005)	

1-9 Electron Beam Melting Furnace Building No. 2, Room B05 This device is used for melting refractory materials using an electron beam on a water-cooled copper hearth ($\phi 100 \times t10$ mm) under high vacuum conditions (10^{-4} Pa). JEOL Ltd.: (1995)	
1-10 High-Frequency Induction Tilt Casting Building No. 3, Room 307 This device can prepare a master alloy ingot by tilt-casting into a mold by high frequency induction heating under inert gas atmosphere. The amount of an alloy that can be prepared at one time is about 70 g in terms of iron. By selecting the optimum crucible material, the maximum temperature can be reached up to 1500 °C. Makabe Giken Co.,Ltd.: VF-HMF100 (2007)	
1-11 Single Roll Melt Spinning Building No. 2, Room B06A This device is used for ultra-rapid cooling of molten metals in a vacuum or an inert gas atmosphere. An alloy is melted in the quartz nozzle and spun by the high-speed rotating copper roller. The melting temperature of the alloy must be below 1200 °C. This machine can also be used as a copper mold casting machine. NISSIN GIKEN Corporation: NEV-A04 (1999)	
1-12 IR Image Furnace for Floating Zone Melting Building No. 3, Room 208 This equipment can obtain highly purified single-crystalline materials by the floating zone melting method using an infrared (IR) beam focused from a halogen lamp. It can melt materials under an arbitrary atmosphere and can be used to obtain single crystals of metals, alloys, intermetallic compounds, and oxides. The equipment can obtain highly purified materials because the materials are melted without the use of a reaction container. Asgal: FZ-SS35WV (1989)	

1-13 Electron Beam Furnace for Floating Zone Melting Building No. 3, Room 208 This equipment can obtain highly purified single-crystalline materials by the floating zone melting method using electron beams. The charged materials can be heated up to 3000 °C in vacuum. JEOL: JEBS-3B (1974)	
1-14 Tungsten Resistivity Element Furnace for Vacuum Heating Building No. 3, Room 208 This furnace can be used to heat and melt samples at a high temperature (up to 1800 °C) using a tungsten mesh heater in vacuum. ULVAC: FHW-50-special specification (1971)	
1-15 High-Frequency Induction Furnace Building No. 2, Room B08 This furnace is capable of melting quantities of various metals (1 kg in the case of iron) in a high vacuum of 2.0×10^{-3} Pa. The charged metals are melted in an appropriate crucible in vacuum or an inert gas atmosphere; they are then cast into a mold by inclining the crucible. The furnace can be used to prepare ingots of raw metals, mother alloys, and metallic glasses. DIAVAC: VMF-1-11 (2004)	
1-16 High-Temperature Floating Zone Furnace for Composite Ceramics Building No. 2, Room B08 This equipment can be used to heat and melt samples at a high temperature (up to above 2000 °C) using a xenon lamp heating system without a crucible. The equipment is used extensively for single-crystal growth and ceramic synthesis at a high melting temperature. Asgal: FZ-20065XHVG (1998)	

1-17 Vacuum Arc Melting Furnace for Small-sized Ingot

Building No. 3, Room 203

The arc-melting furnace can melt charged materials and fabricate polycrystalline material ingots. The material is melted by means of an electrical arc, which is generated conventionally by a power of 2 to 6 kW. It is used extensively to melt and cast metals, alloys, intermetallic compounds, and some oxides, by increasing the temperature to above 3,000 °C.

obtainable sample size: [disk-shaped sample] max ϕ 30 mm $\times$ 10 mm, [rod-shaped sample] ϕ 8-10 mm $\times$ 90 mmL

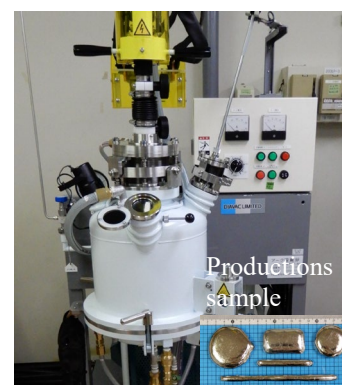
DIAVAC: ACM-01 (1986)

**1-18 Vacuum Arc Melting Furnace for Large-sized Ingot**

Building No. 3, Room 203

This is a larger version to Vacuum Arc Melting Furnace for Small-sized Ingot (Max output: 300 A) (listed up as # 1-19), and equipped with a turbo-molecular pump to evacuate the chamber. We can obtain refractory alloy ingots with a dimension of 50 mm in diameter and 10 mm in thickness.

DIAVAC: ACM-S14TMP-M (2020)

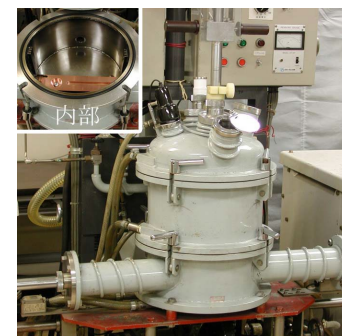
**1-19 Arc-Melting Furnace with Horizontal Traveling Hearth**

Building No. 3, Room 203

This arc-melting furnace exhibits a performance similar to that of a conventional furnace (such as the one listed in 1-19). In addition, the furnace is attached with a system that shifts the copper hearth horizontally at a speed of 5–60 mm/h. Therefore, it can fabricate long rod-shaped specimens with elongated and coarsened grains.

obtainable sample size: [rod-shaped sample] ϕ 10 mm $\times$ 290 mmL

DIAVAC: ACM-S-6 (1985)

**1-20 Programmable Furnace with MoSi₂ Heater**

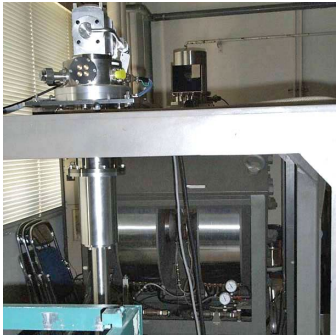
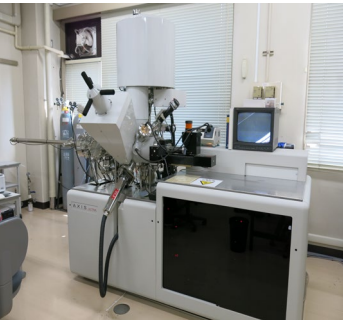
Building No. 3, Room 116

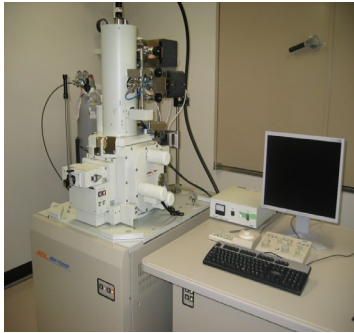
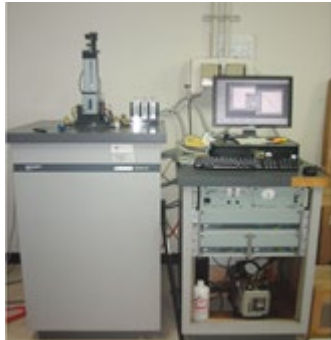
This furnace, which is equipped with a MoSi₂ heater, can heat up to a maximum temperature of 1600 °C in air. The furnace can also be used for the synthesis of complex oxides by reaction sintering and for the fabrication of various sintered compacts.

NECCO: 850-M-120 $\times$ 120 (1998)



2. Material analysis group

2-1 Magnetic Property Measurement System	
Building No. 2, Room 107	
This measurement system can be used to characterize the magnetic properties of magnetic materials (mainly thin-film samples). The maximum magnetic field is 2 T. The magnetization can be measured. TAMAKAWA CO.,LTD: TM-VSM2614HGC-KIT (2014)	
2-2 X-ray Diffractometer (Micro-Area Type)	
Building No. 2, Room 103	
This X-ray diffractometer can analyze fine precipitation in specimens using a micro X-ray collection device, CBO-f. Rigaku: UltimaIV/MAJ (2009)	
2-3 X-ray Diffractometer (Horizontal Sample Setting Type)	
Building No. 2, Room 103	
A high-performance detector (D/teX Ultra) enables a high-speed analysis, up to 100 times compared with a conventional scintillation counter. In addition, a trace element analysis can be performed. Rigaku: UltimaIV/SG (2012)	
2-4 X-ray Photoelectron Spectrometer (XPS)	
Building No. 2, Room 106	
The composition of a sample can be analyzed by measuring the energy and intensity of photoelectrons generated under irradiation of X-rays. The position of peak energy determines the chemical state, and the surface with a depth of several nanometers can also be analyzed. The sample transfer container system enables the analysis of chemically-treated samples without exposure to the atmosphere. SHIMAZDU Co.: KRATOS AXIS-Ultra DLD (2009)	

2-5 Field Emission Scanning Electron Microscope (FE-SEM) Building No. 2, Room 217 High-resolution observations on the order of 1 nm in secondary electron images can be achieved by using the FE electron gun. This equipment can analyze complex surfaces, such as tensile-fractured surfaces. Insulation materials can be observed using various observation modes without pre-treatment. JEOL: JSM-7500F (2009)	
2-6 Field Emission Electron Probe Micro-Analyzer (FE-EPMA) Building No. 2, Room 106 FE-EPMA with a small probe of 40 nm and a high resolution of 3 nm enables high-precision composition analysis using a wavelength dispersive X-ray spectrometer, which can detect elements from boron to uranium. The attached EBSD system analyzes the crystal orientation of specimens. JEOL: JXA-8530F (2009)	
2-7 Scanning Electron Microscope (Tungsten Filament) (W-SEM) Building No. 2, Room 107 This thermionic-emission gun with a tungsten filament provides high-resolution secondary electron images (SEI) and back-scattered electron (BSE) images of metallic and inorganic materials. The chemical compositions of samples can be determined using the attached EDX system. The maximum size of a specimen that can be installed in the analysis chamber is 200 mm in diameter and 80 mm in thickness. Hitachi High Technologies: S-3400N (2008)	
2-8 Superconducting Quantum Interference Device (SQUID) Magnetometer Building No. 2, Room 107 Quantum Design's MPMS magnetometry provides users with a superconducting quantum interference device, SQUID, which has a sensitivity $\leq 10^{-6}$ emu under a temperature range of 2–400 K and a magnetic field control below 5 T. AC magnetic measurements can also be performed in a frequency range of 0.01–1500 Hz. Quantum Design: MPMS-5S (1997)	

2-9 Differential Scanning Calorimetry (DSC)

Building No. 2, Room 215

The high temperature Differential Scanning Calorimeter (DSC) is designed to quantitatively measure the energy absorbed or released by samples as they are heated; from room temperature up to 1400 °C. The DSC can measure many thermodynamic properties of samples including the: (ΔH) Transition & Reaction Enthalpies; (TM) Temperatures of Melting & Phase Transformations; (TG) Temperature and energy change of Glass Transition & Crystallization; Tests are performed with an inert reference held in a shared chamber with the sample. Both reference and sample are exposed to the same heating rates and environment, and thermodynamic properties can then be calculated by comparison. The instrument is not designed to handle sample decomposition or volatility and should not be used with reactive samples.

Netzsch Japan: DSC404C (2007)

**2-10 Conventional Type Thermal Analysis Measurement System (DTA, DSC, TMA)**

Building No. 2, Room 215

Differential thermal analysis (DTA), differential scanning calorimetry (DSC), and thermomechanical analysis (TMA) between the sample and reference are monitored against time or temperature, while the temperature of the sample is programmed in a specified atmosphere. A aluminum, platinum, or alumina crucible can be used while monitoring the DTA and DSC properties of the sample. The system delivers an extended temperature range from ambient temperature to 1300 °C for DTA, to 1200 °C for DSC and to 1500 °C for TMA. The cooling unit can be used to measure the DSC in a temperature ranging from -150 °C to 500 °C.

SISeiko Instruments Inc.: EXSTAR 6000 series, TMA/SS 6200, TG/DTA 6300, DSC 6200 6300 (2007)

**2-11 Wide and Small Angle X-ray Diffractometer (rotating anode X-ray source)**

Building No. 2, Room 103

This device with a 18 kW rotating anode X-ray source, is compatible with the small-angle scattering method (SAXS) and the powder diffraction method (XRD). SAXS method, which measures X-ray scattering intensity with a scattering angle of several degrees or less, allows us to analyze the particle shape and size together with their distribution. In addition, the common XRD method is a powerful method to identify the structure of substances by combining a high-intensity radiation source, a monochromator and a scintillation counter. As an option, it is also possible to analyze the structure of a thin film using a parallel beam optical system.

Rigaku: UltraX18VB3-450 (2020)



2-12 Vibrating Sample Magnetometer (VSM)

Building No. 2, Room B05

Magnetic properties of bulk, powder, and thin-film materials can be measured with high sensitivity in a temperature range of 77 K to 1200 K using this magnetometer. The maximum applicable magnetic field is 1.5 T and the magnetization range is 10^{-3} to 10^2 emu. Magnetization curves at an arbitrary temperature, thermal magnetization curves under a constant magnetic field, temperature changes during magnetization, spontaneous magnetization, and Curie and Neel temperatures can also be obtained. The measurement of magnetostriction by using Strain-Gauge under applying magnetic field is also possible.

Toei Scientific Industrial: VSM-5 (1995)

**2-13 Laue X-ray Back Scattering by Digital CCD Camera**

Building No. 2, Room 110

The constituent instruments of this system are 1) X-ray generator, 2) Laue back scattering optical system, 3) Sample stage, 4) Cooling-type CCD digital camera, 5) PC, and 6) Orientation-analyzing software. A tungsten target is used as the X-ray tube and the maximum load power is 3 kW. A four-axis goniometer is commonly used in the electric discharge machine. Diffraction spots can be immediately obtained on the PC using the CCD digital camera.

Rigaku: RASCO-IIBLA (2014)

**2-14 Seebeck Coefficient/Electrical Resistivity Measurement System**

Building No. 3, Room 308

The Seebeck coefficient and electrical resistivity can be measured by the steady direct-current method and by the four-point probe method. The operating temperature ranges from room temperature to 1000 °C. The available sample shape is a rod or a prism with a length of 5~2 mm.

Advance Riko: ZEM-3 (2015)

**2-15 Laser flash apparatus for thermal diffusivity and conductivity measurements**

Building No. 3, Room 308

The Laser Flash Apparatus is useful to measure the thermal characteristics (thermal diffusivity, specific heat capacity, thermal conductivity) of solid materials such as metals, ceramics, glass, carbon, and plastics. Since it is easier to measure than the steady-state method and the data obtained is so reliable, it should be the most effective method to obtain the thermal conductivity.

Advance Riko: TC-7000S (2020)

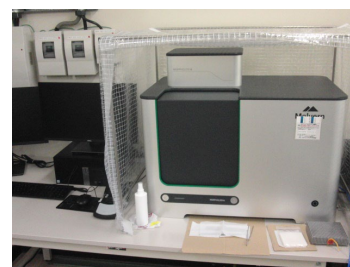


2-16 Static particle image analyzer

Building No. 3, Room 307

This device can accurately evaluate the morphology of powder particles by static image analysis. A series of operations from sample dispersion to measurement can be performed automatically. The imaging optical system can be selected from transmission or incident-light mode. The binarized image and characteristic parameters are automatically recorded. It can handle many types of powder samples such as metals, ceramics, and organic substances.

Malvern Panalytical: Morphologi 4 (2021)

**2-17 Flat / Cross Section Ion Milling System**

Building No. 3, Room 310

This apparatus allows us to polish the sample using the sputtering phenomena by argon ion beam irradiation. In the planar milling mode, it is possible to remove the surface contaminated layer, fine scratches, and strain of the sample specimen. In the cross-section milling mode, focused argon ion beam processing provides a sound cross-section surface for microstructural observation. We can obtain high-quality image and analysis via scanning electron microscope (SEM) and backscattered electron diffraction (EBSD) using the specimen polished by the apparatus.

Hitachi High-Tech Corporation: IM4000PLUS (2022)

**2-18 Micro Vickers Hardness Tester**

Building No. 2, Room B01

The Vickers hardness tester determines the hardness of a material by pressing a diamond pyramid-shaped indenter against a test piece and measuring the load and the length of the diagonal of the indentation.

Shimadzu Corporation : HMV-2ADW (2024)

